

TPD1E0B04 适用于 USB Type-C 和天线保护的单通道 ESD 保护二极管

1 特性

- IEC 61000-4-2 4 级（接触）静态放电 (ESD) 保护
 - $\pm 8\text{kV}$ 接触放电
 - $\pm 9\text{kV}$ 气隙放电
- IEC 61000-4-4 瞬态放电 (EFT) 保护
 - 80A (5/50ns)
- IEC 61000-4-5 浪涌保护
 - 1.7A (8/20 μs)
- IO 电容: 0.13pF（典型值），0.15pF（最大值）
- 直流击穿电压: 6.7V（典型值）
- 超低泄漏电流: 10nA（最大值）
- 低 ESD 钳位电压
- 支持速率最高达 20Gbps 的高速接口
- 低插入损耗: 大于 30GHz（-3dB 带宽）
- 工业温度范围: -40°C 至 +125°C
- 超小型 0201 封装

2 应用

- 终端设备
 - 便携式计算机和台式机
 - 手机和平板电脑
 - 机顶盒
 - 电视和监视器
 - USB 软件狗
 - 扩展坞
- 接口
 - USB Type-C
 - Thunderbolt 3
 - USB 3.1 第 2 代
 - 高清多媒体接口 (HDMI) 2.0/1.4
 - USB 3.0
 - DisplayPort 1.3
 - PCI Express 3.0
 - 天线

3 说明

TPD1E0B04 是一款双向瞬态电压抑制器 (TVS) ESD 保护二极管阵列，用于为 USB Type-C 和 Thunderbolt 3 电路提供保护。TPD1E0B04 的额定 ESD 冲击消散值等于 IEC 61000-4-2（4 级）国际标准中规定的最高水平。

此器件 特有一个 0.13pF IO 电容（每通道），适合于保护速率高达 20Gbps 的高速接口，例如 USB 3.1 Gen2、Thunderbolt 3 以及天线接口。低动态电阻和低钳位电压可针对瞬变事件提供系统级保护。

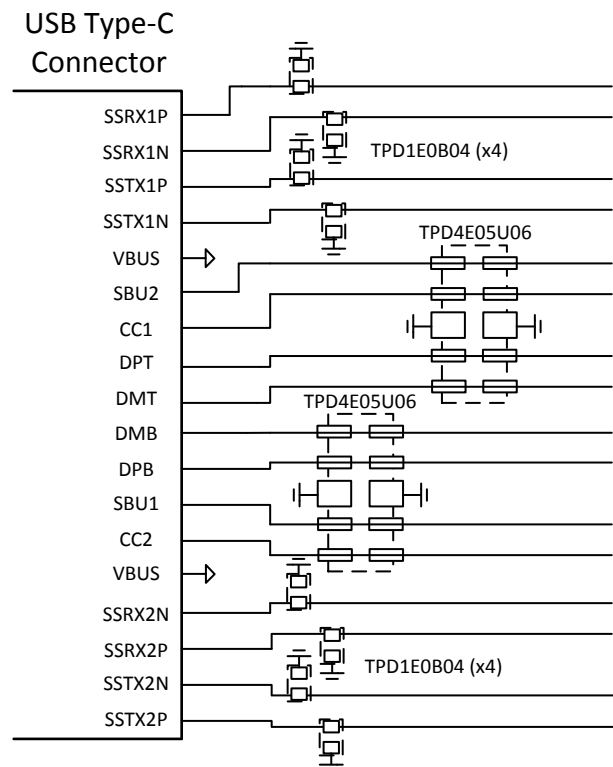
TPD1E0B04 采用符合行业标准的 0201 (DPL) 封装。

器件信息⁽¹⁾

器件型号	封装	封装尺寸（标称值）
TPD1E0B04	X2SON (2)	0.60mm x 0.30mm

(1) 要了解所有可用封装，请参见数据表末尾的可订购产品附录。

典型应用



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4 修订历史记录

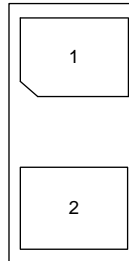
Changes from Original (March 2016) to Revision A

Page

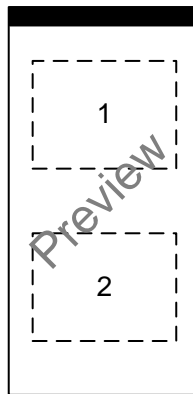
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5 Pin Configuration and Functions

**DPL Package
2-Pin X2SON
Top View**



**DPY Package
2-Pin X1SON
Top View**



Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
1	IO	I/O	ESD Protected Channel. If used as ESD IO, connect pin 2 to ground
2	IO	I/O	ESD Protected Channel. If used as ESD IO, connect pin 1 to ground

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Electrical fast transient	IEC 61000-4-5 (5/50 ns)		80	A
Peak pulse	IEC 61000-4-5 power ($t_p - 8/20 \mu\text{s}$)		15	W
	IEC 61000-4-5 current ($t_p - 8/20 \mu\text{s}$)		1.7	A
T_A	Operating free-air temperature	-40	125	°C
T_{stg}	Storage temperature	-65	155	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

		VALUE	UNIT
$V_{\text{(ESD)}}$ Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2500	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 ESD Ratings—IEC Specification

		VALUE	UNIT
$V_{\text{(ESD)}}$ Electrostatic discharge	IEC 61000-4-2 contact discharge	±8000	V
	IEC 61000-4-2 air-gap discharge	±9000	

6.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{IO}	Input pin voltage	-3.6	3.6	V
T_A	Operating free-air temperature	-40	125	°C

6.5 Thermal Information

THERMAL METRIC ⁽¹⁾		TPD1E0B04	UNIT
		DPL (X2SON)	
		2 PINS	
$R_{\theta\text{JA}}$	Junction-to-ambient thermal resistance	582	°C/W
$R_{\theta\text{JC(top)}}$	Junction-to-case (top) thermal resistance	264.5	°C/W
$R_{\theta\text{JB}}$	Junction-to-board thermal resistance	394.4	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	36.4	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	394.4	°C/W
$R_{\theta\text{JC(bot)}}$	Junction-to-case (bottom) thermal resistance	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.6 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{RWM}	Reverse stand-off voltage	$I_{IO} < 10 \text{ nA}$	-3.6		3.6	V
V_{BRF}	Breakdown voltage, IO pin to GND	Measured as the maximum voltage before device snaps back into V_{HOLD} voltage		6.7		V
V_{BRR}	Breakdown voltage, GND to IO pin	Measured as the maximum voltage before device snaps back into V_{HOLD} voltage		-6.7		V
V_{HOLD}	Holding voltage	$I_{IO} = 1 \text{ mA}$, $T_A = 25^\circ\text{C}$	5	5.7	6.5	V
V_{CLAMP}	Clamping voltage	$I_{PP} = 1 \text{ A}$, TLP, from IO to GND		7.2		V
		$I_{PP} = 5 \text{ A}$, TLP, from IO to GND		10.1		
		$I_{PP} = 16 \text{ A}$, TLP, from IO to GND		19		
		$I_{PP} = 1 \text{ A}$, TLP, from GND to IO		7.2		
		$I_{PP} = 5 \text{ A}$, TLP, from GND to IO		10.1		
		$I_{PP} = 16 \text{ A}$, TLP, from GND to IO		19		
I_{LEAK}	Leakage current, IO to GND	$V_{IO} = \pm 2.5 \text{ V}$			10	nA
R_{DYN}	Dynamic resistance	IO to GND		1		Ω
		GND to IO		1		
C_L	Line capacitance	$V_{IO} = 0 \text{ V}$, $f = 1 \text{ MHz}$, IO to GND $T_A = 25^\circ\text{C}$		0.13	0.15	pF

6.7 Typical Characteristics

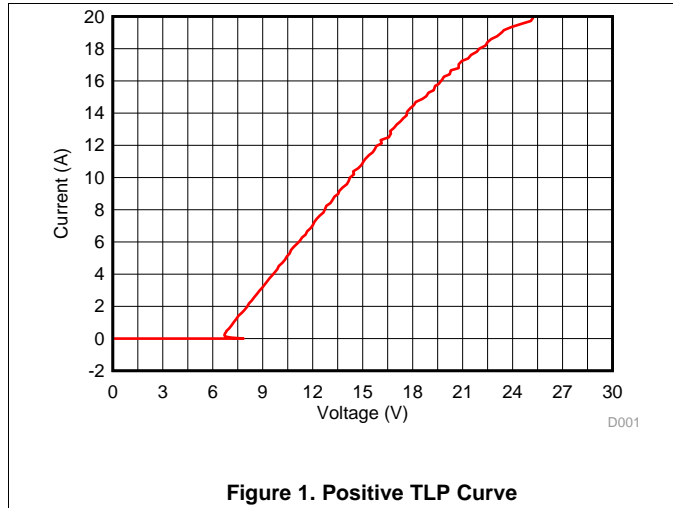


Figure 1. Positive TLP Curve

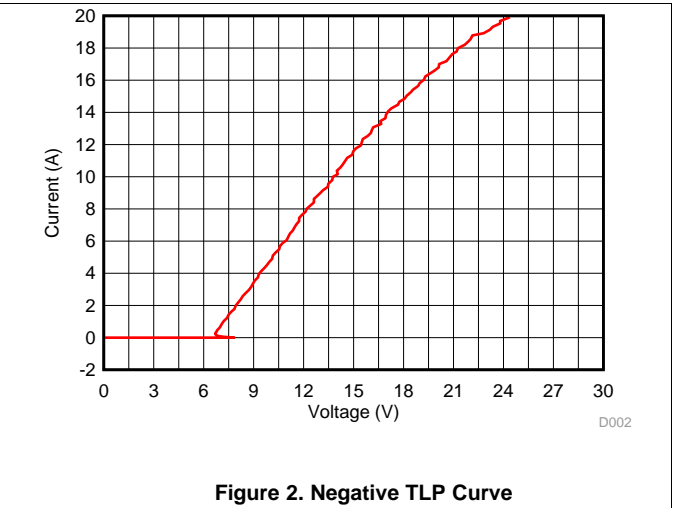


Figure 2. Negative TLP Curve

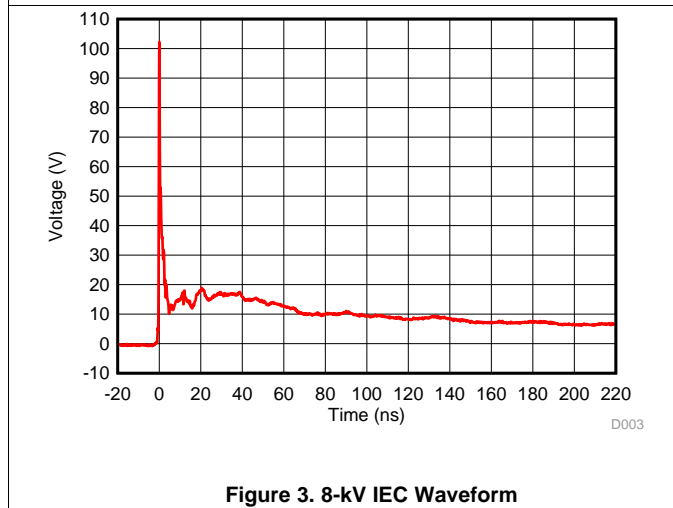


Figure 3. 8-kV IEC Waveform

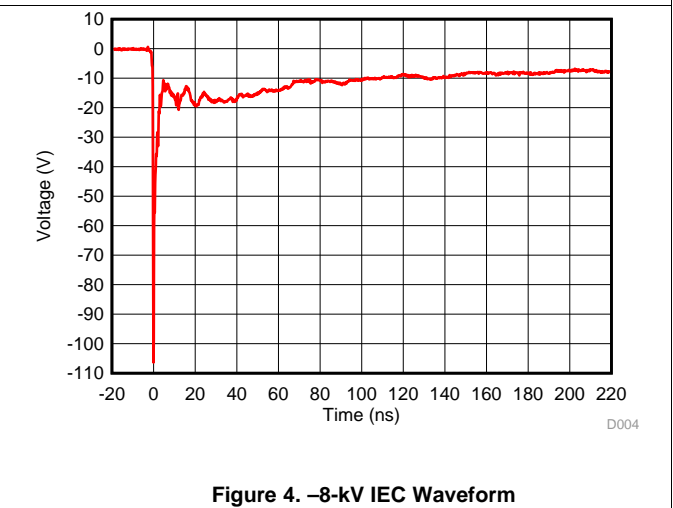


Figure 4. -8-kV IEC Waveform

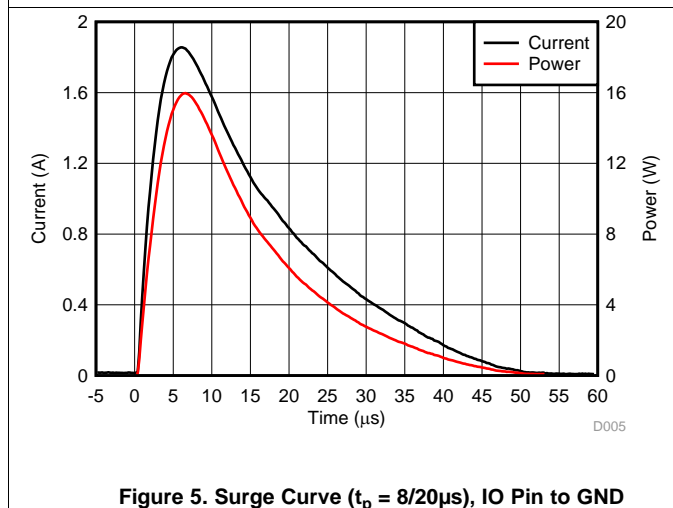


Figure 5. Surge Curve ($t_p = 8/20\mu s$), IO Pin to GND

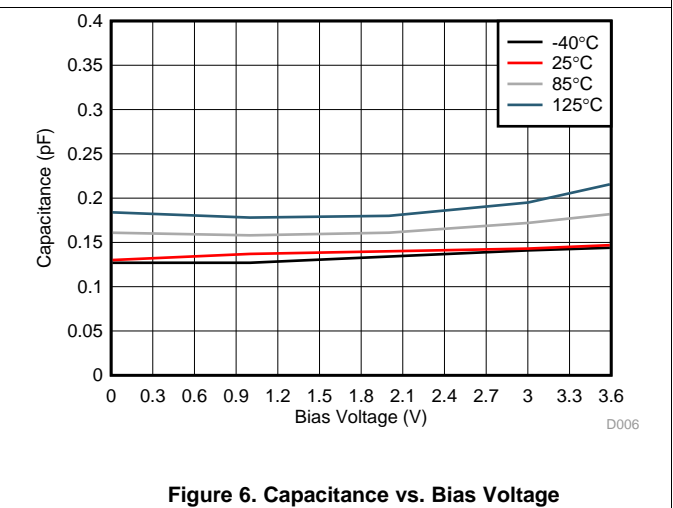
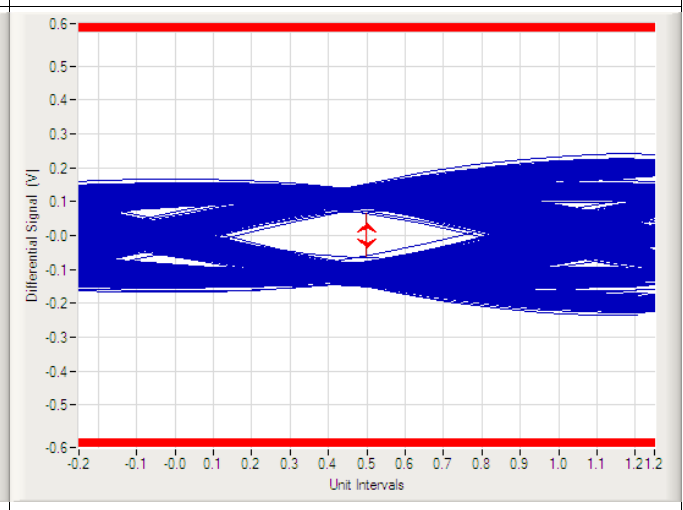
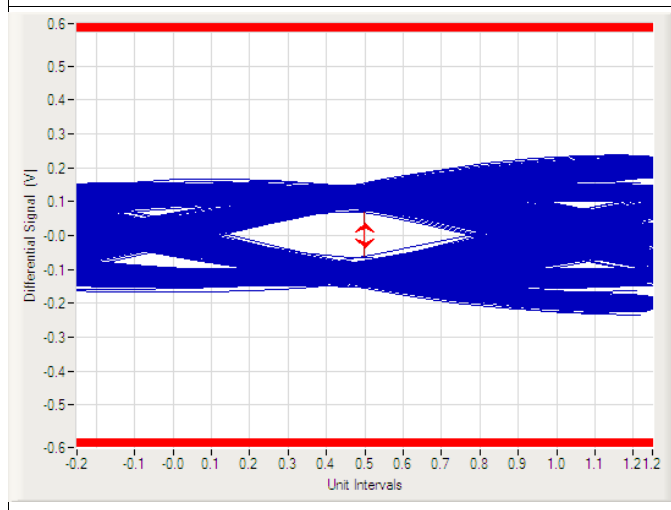
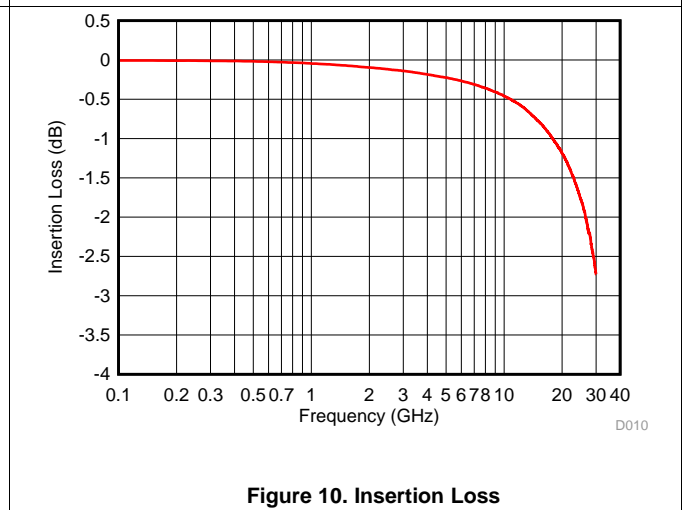
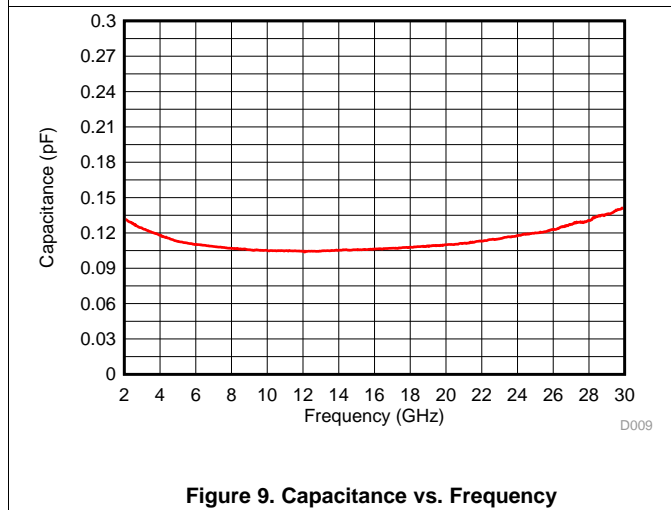
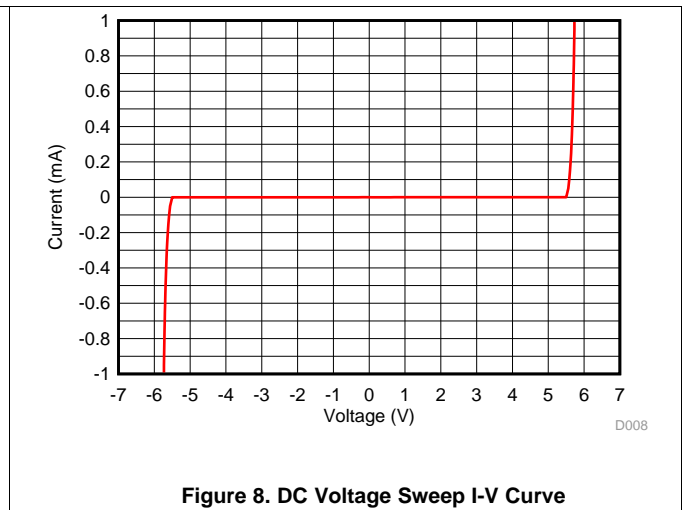
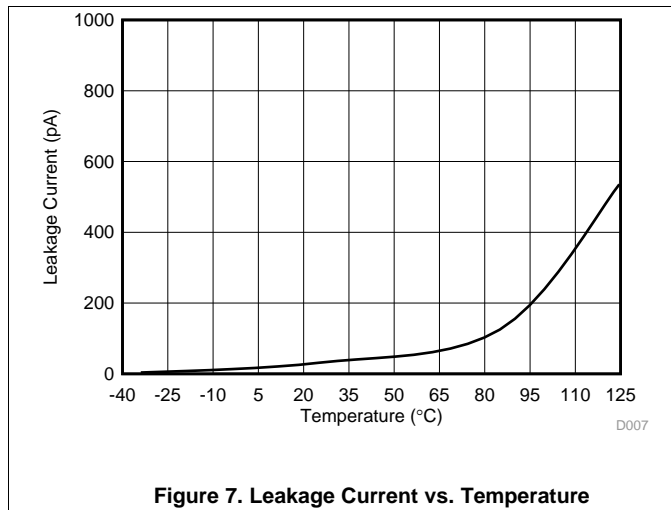


Figure 6. Capacitance vs. Bias Voltage

Typical Characteristics (continued)

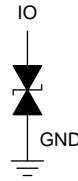


7 Detailed Description

7.1 Overview

The TPD1E0B04 device is a bidirectional ESD Protection Diode with ultra-low capacitance. This device can dissipate ESD strikes at the maximum level specified by the IEC 61000-4-2 International Standard (contact). The ultra-low capacitance makes this device ideal for protecting any super high-speed signal pins including Thunderbolt 3. The low capacitance allows for extremely low losses even at RF frequencies such as USB 3.1 Gen 2, Thunderbolt 3, or antenna applications.

7.2 Functional Block Diagram



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7.3 Feature Description

7.3.1 IEC 61000-4-2 ESD Protection

The I/O pins can withstand ESD events up to ± 8 -kV contact and ± 9 -kV air gap. An ESD-surge clamp diverts the current to ground.

7.3.2 IEC 61000-4-4 EFT Protection

The I/O pins can withstand an electrical fast transient burst of up to 80 A (5/50 ns waveform, 4 kV with 50- Ω impedance). An ESD-surge clamp diverts the current to ground.

7.3.3 IEC 61000-4-5 Surge Protection

The I/O pins can withstand surge events up to 1.7 A and 15 W (8/20 μ s waveform). An ESD-surge clamp diverts this current to ground.

7.3.4 IO Capacitance

The capacitance between each I/O pin to ground is 0.13 pF (typical) and 0.15 pF (maximum). This device supports data rates in excess of 20 Gbps.

7.3.5 DC Breakdown Voltage

The DC breakdown voltage of each I/O pin is ± 6.7 V (typical). This ensures that sensitive equipment is protected from surges above the reverse standoff voltage of ± 3.6 V.

7.3.6 Ultra Low Leakage Current

The I/O pins feature an ultra-low leakage current of 10 nA (maximum) with a bias of ± 2.5 V

7.3.7 Low ESD Clamping Voltage

The I/O pins feature an ESD clamp that is capable of clamping the voltage to 10.1 V ($I_{PP} = 5$ A).

7.3.8 Supports High Speed Interfaces

This device is capable of supporting high speed interfaces in excess of 20 Gbps, because of the extremely low IO capacitance.

7.3.9 Industrial Temperature Range

This device features an industrial operating range of -40°C to $+125^{\circ}\text{C}$.

Feature Description (continued)

7.3.10 Industry Standard Package

The layout of this device makes it simple and easy to add protection to an existing layout. The package is offered in industry standard 0201 footprint, requiring minimal modification to an existing layout.

7.4 Device Functional Modes

The TPD1E0B04 device is a passive integrated circuit that triggers when voltages are above V_{BRF} or below V_{BRR} . During ESD events, voltages as high as ± 9 kV (air) can be directed to ground via the internal diode network. When the voltages on the protected line fall below the trigger levels of TPD1E0B04 (usually within 10s of nanoseconds) the device reverts to passive.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPD1E0B04 is a diode type TVS which is used to provide a path to ground for dissipating ESD events on high-speed signal lines between a human interface connector and a system. As the current from ESD passes through the TVS, only a small voltage drop is present across the diode. This is the voltage presented to the protected IC. The low R_{DYN} of the triggered TVS holds this voltage, V_{CLAMP} , to a safe level for the protected IC.

8.2 Typical Applications

8.2.1 USB Type-C Application

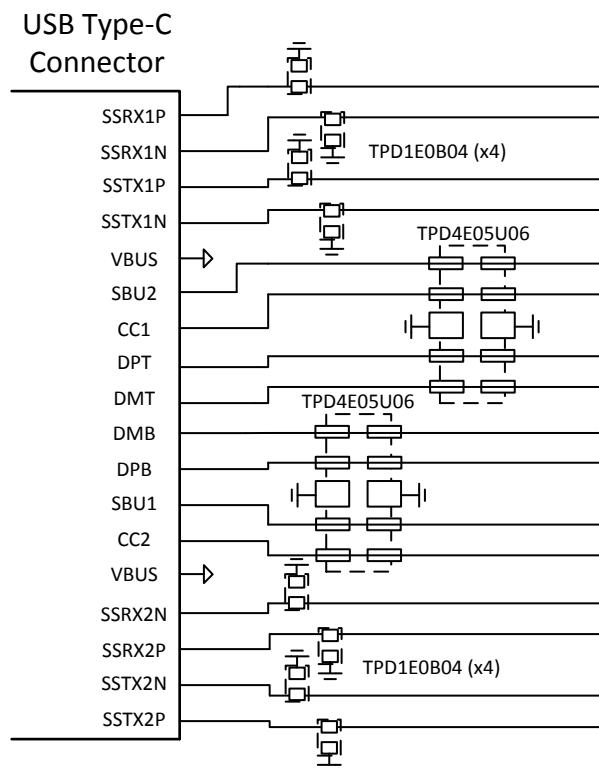


Figure 13. USB Type-C for Thunderbolt 3 ESD Schematic

8.2.1.1 Design Requirements

For this design example eight TPD1E0B04 devices and two TPD4E05U06 devices are being used in a USB Type-C for Thunderbolt 3 application. This provides a complete ESD protection scheme.

Given the Thunderbolt 3 application, the parameters listed in [Table 1](#) are known.

Table 1. Design Parameters

DESIGN PARAMETER	VALUE
Signal range on superspeed Lines	0 V to 3.6 V
Operating frequency on superspeed Lines	up to 10 GHz
Signal range on CC, SBU, and DP/DM Lines	0 V to 5 V
Operating frequency on CC, SBU, and DP/DM Lines	up to 480 MHz

8.2.1.2 Detailed Design Procedure

8.2.1.2.1 Signal Range

The TPD1E0B04 supports signal ranges between -3.6 V and 3.6 V , which supports the SuperSpeed pairs on the USB Type-C application. The TPD4E05U06 supports signal ranges between 0 V and 5.5 V , which supports the CC, SBU, and DP-DM lines.

8.2.1.2.2 Operating Frequency

The TPD1E0B04 has a 0.13 pF (typical) capacitance, which supports the Thunderbolt 3 data rates of 20 Gbps . The TPD4E05U06 has a 0.5-pF (typical) capacitance, which easily supports the CC, SBU, and DP-DM data rates.

8.2.1.3 Application Curves

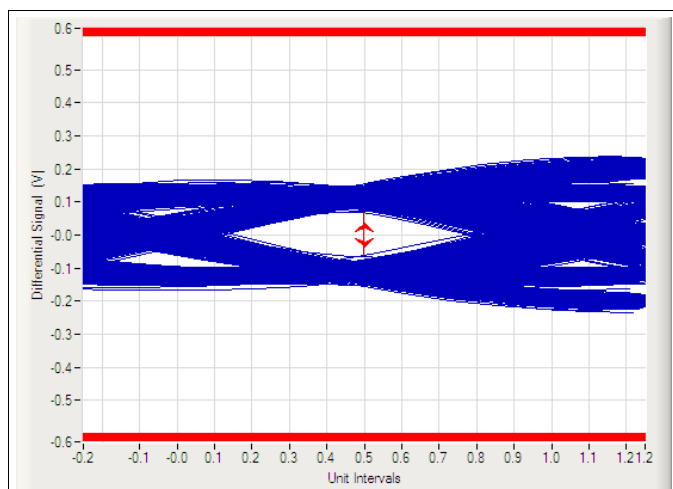


Figure 14. USB 3.1 Gen 2 10-Gbps Eye Diagram (Bare Board)

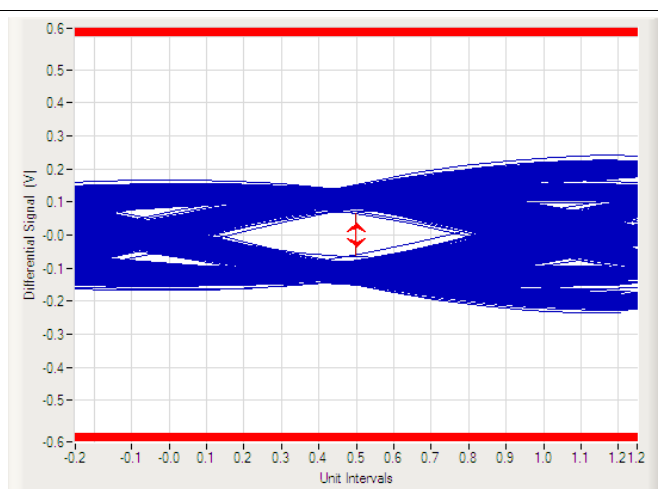
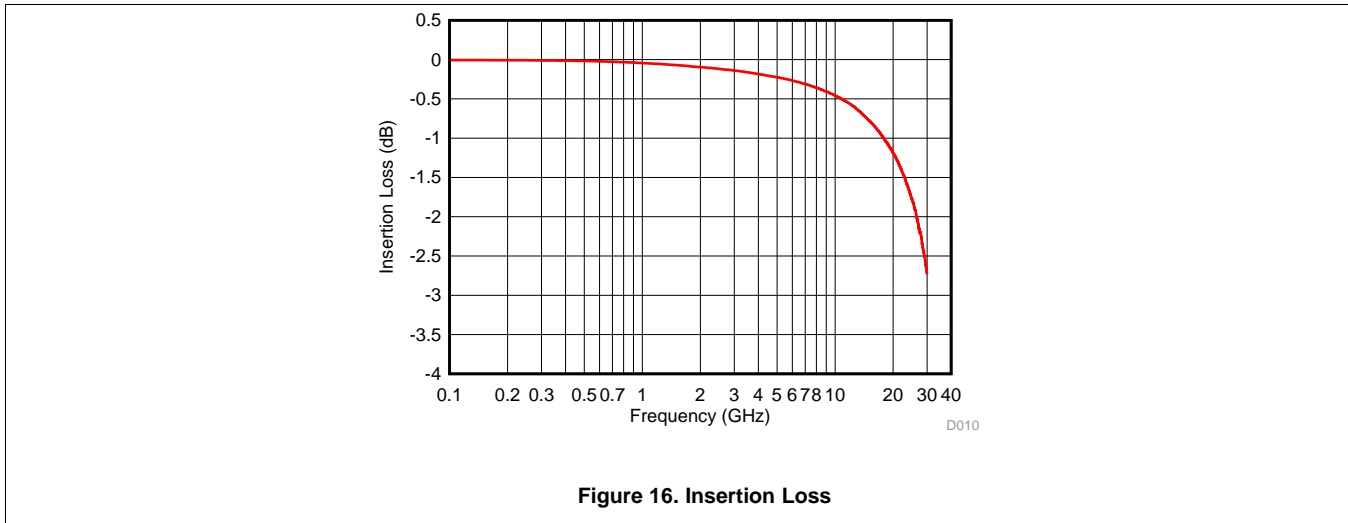


Figure 15. USB 3.1 Gen 2 10-Gbps Eye Diagram (with TPD1E0B04)



8.2.2 WiFi Antenna Application

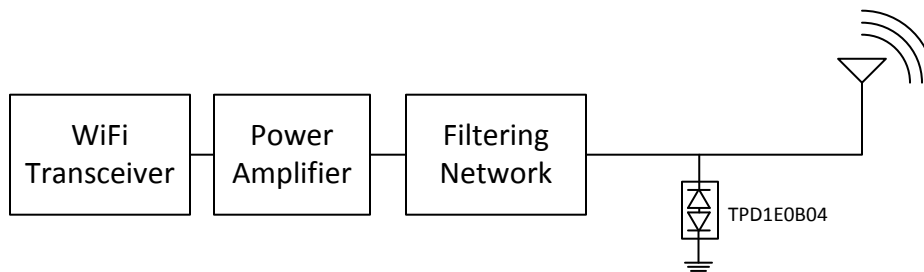


Figure 17. WiFi Antenna Schematic

8.2.2.1 Design Requirements

For this design example one TPD1E0B04 device for a 5-GHz WiFi antenna application. This provides a complete ESD protection scheme.

Given the WiFi antenna application, the parameters listed in [Table 2](#) are known.

Table 2. Design Parameters

DESIGN PARAMETER	VALUE
Signal range	-3.16 V to +3.16 V
Operating frequency	5.170 GHz to 5.835 GHz

8.2.2.2 Detailed Design Procedure

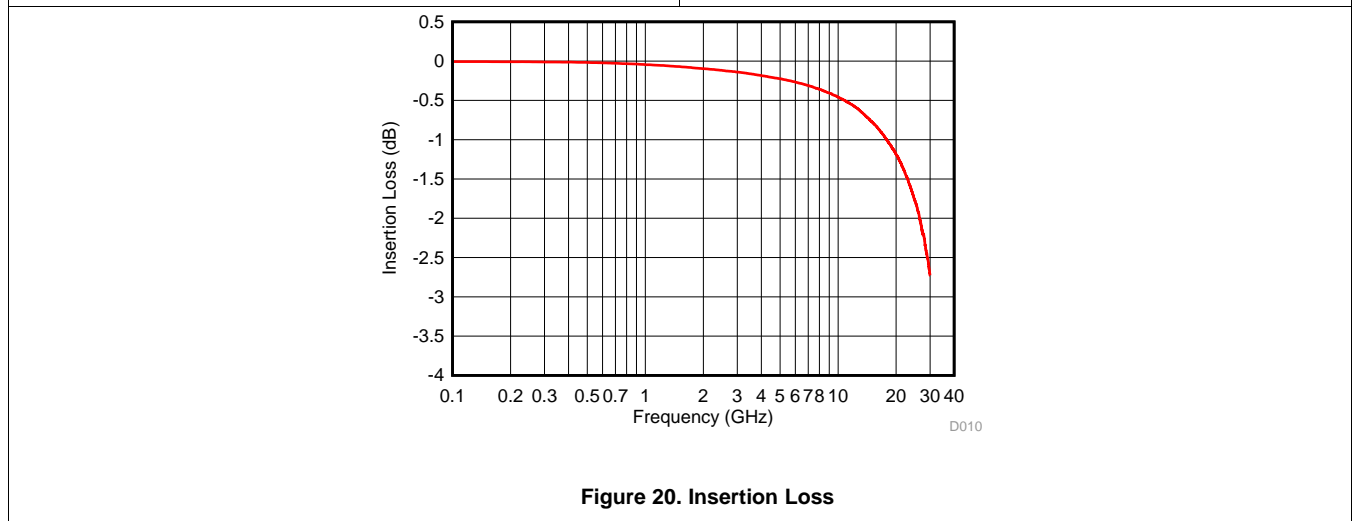
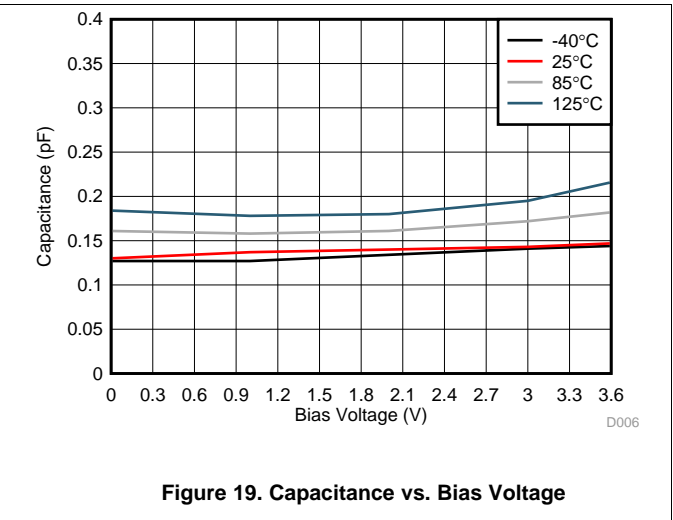
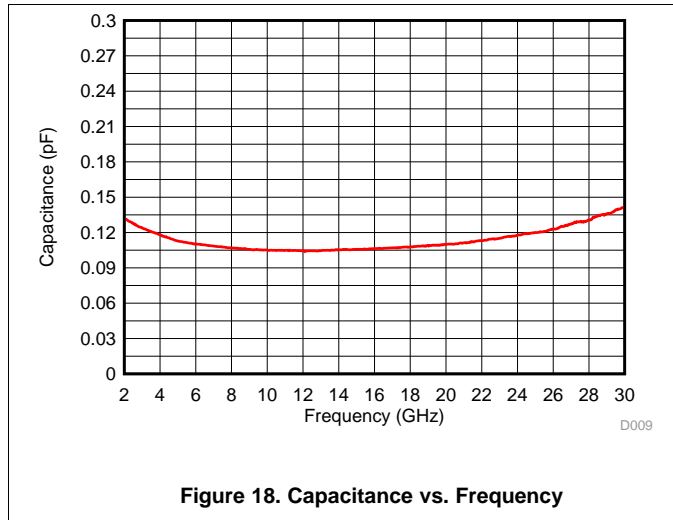
8.2.2.2.1 Signal Range

The TPD1E0B04 supports signal ranges between -3.6 V and 3.6 V, which supports the antenna signal range. The signal range shown assumes maximum transmit power of 200 mW into a 50-Ω antenna.

8.2.2.2.2 Operating Frequency

The TPD1E0B04 has a 0.13 pF (typical) capacitance, which supports extremely high data rates. The capacitance vs. frequency and bias voltages are exceedingly low, allowing for very low RF loss and known impedance characteristics. Since capacitance and loss changes very little across the operating frequencies, there must be minimal disturbance on the line.

8.2.2.3 Application Curves



9 Power Supply Recommendations

This device is a passive ESD device so there is no need to power it. Take care not to violate the recommended I/O specification to ensure the device functions properly.

10 Layout

10.1 Layout Guidelines

- The optimum placement is as close to the connector as possible.
 - EMI during an ESD event can couple from the trace being struck to other nearby unprotected traces, resulting in early system failures.
 - The PCB designer must minimize the possibility of EMI coupling by keeping any unprotected traces away from the protected traces which are between the TVS and the connector.
- Route the protected traces as straight as possible.
- Eliminate any sharp corners on the protected traces between the TVS and the connector by using rounded corners with the largest radii possible.
 - Electric fields tend to build up on corners, increasing EMI coupling.

10.2 Layout Example

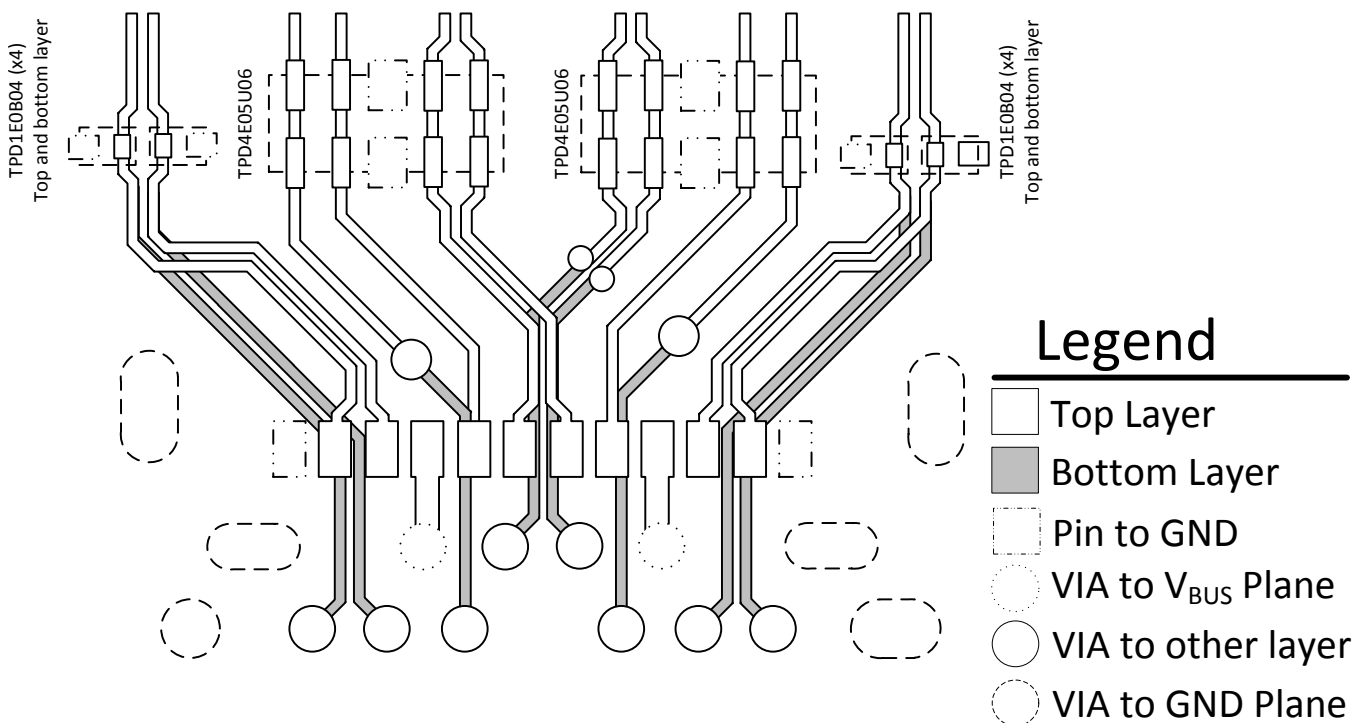


Figure 21. USB Type-C Mid-Mount, Hybrid Connector ESD Layout

11 器件和文档支持

11.1 文档支持

11.1.1 相关文档

相关文档请参见以下部分：

《TPD1E0B04 评估模块用户指南》，[SLVUAN6](#)

11.2 接收文档更新通知

如需接收文档更新通知，请访问 [ti.com](#) 上的器件产品文件夹。点击右上角的提醒我 (Alert me) 注册后，即可每周定期收到已更改的产品信息。有关更改的详细信息，请查阅已修订文档中包含的修订历史记录。

11.3 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](#), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 商标

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

11.5 静电放电警告



ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

11.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPD1E0B04DPLR	Active	Production	X2SON (DPL) 2	15000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8
TPD1E0B04DPLR.B	Active	Production	X2SON (DPL) 2	15000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8
TPD1E0B04DPLRG4.B	Active	Production	X2SON (DPL) 2	15000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8
TPD1E0B04DPLT	Active	Production	X2SON (DPL) 2	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8
TPD1E0B04DPLT.B	Active	Production	X2SON (DPL) 2	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8
TPD1E0B04DPYR	Active	Production	X1SON (DPY) 2	10000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	5D
TPD1E0B04DPYR.B	Active	Production	X1SON (DPY) 2	10000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	5D
TPD1E0B04DPYRG4.B	Active	Production	X1SON (DPY) 2	10000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	5D
TPD1E0B04DPYT	Active	Production	X1SON (DPY) 2	250 SMALL T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	5D
TPD1E0B04DPYT.B	Active	Production	X1SON (DPY) 2	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	5D

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPD1E0B04DPLR	X2SON	DPL	2	15000	178.0	8.4	0.36	0.66	0.33	2.0	8.0	Q1
TPD1E0B04DPLT	X2SON	DPL	2	250	178.0	8.4	0.36	0.66	0.33	2.0	8.0	Q1
TPD1E0B04DPYR	X1SON	DPY	2	10000	180.0	8.4	0.67	1.15	0.46	2.0	8.0	Q2
TPD1E0B04DPYT	X1SON	DPY	2	250	180.0	8.4	0.67	1.15	0.46	2.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPD1E0B04DPLR	X2SON	DPL	2	15000	205.0	200.0	33.0
TPD1E0B04DPLT	X2SON	DPL	2	250	205.0	200.0	33.0
TPD1E0B04DPYR	X1SON	DPY	2	10000	210.0	185.0	35.0
TPD1E0B04DPYT	X1SON	DPY	2	250	210.0	185.0	35.0

GENERIC PACKAGE VIEW

DPY 2

X1SON - 0.45 mm max height

1 x 0.6 mm

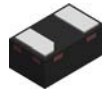
PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



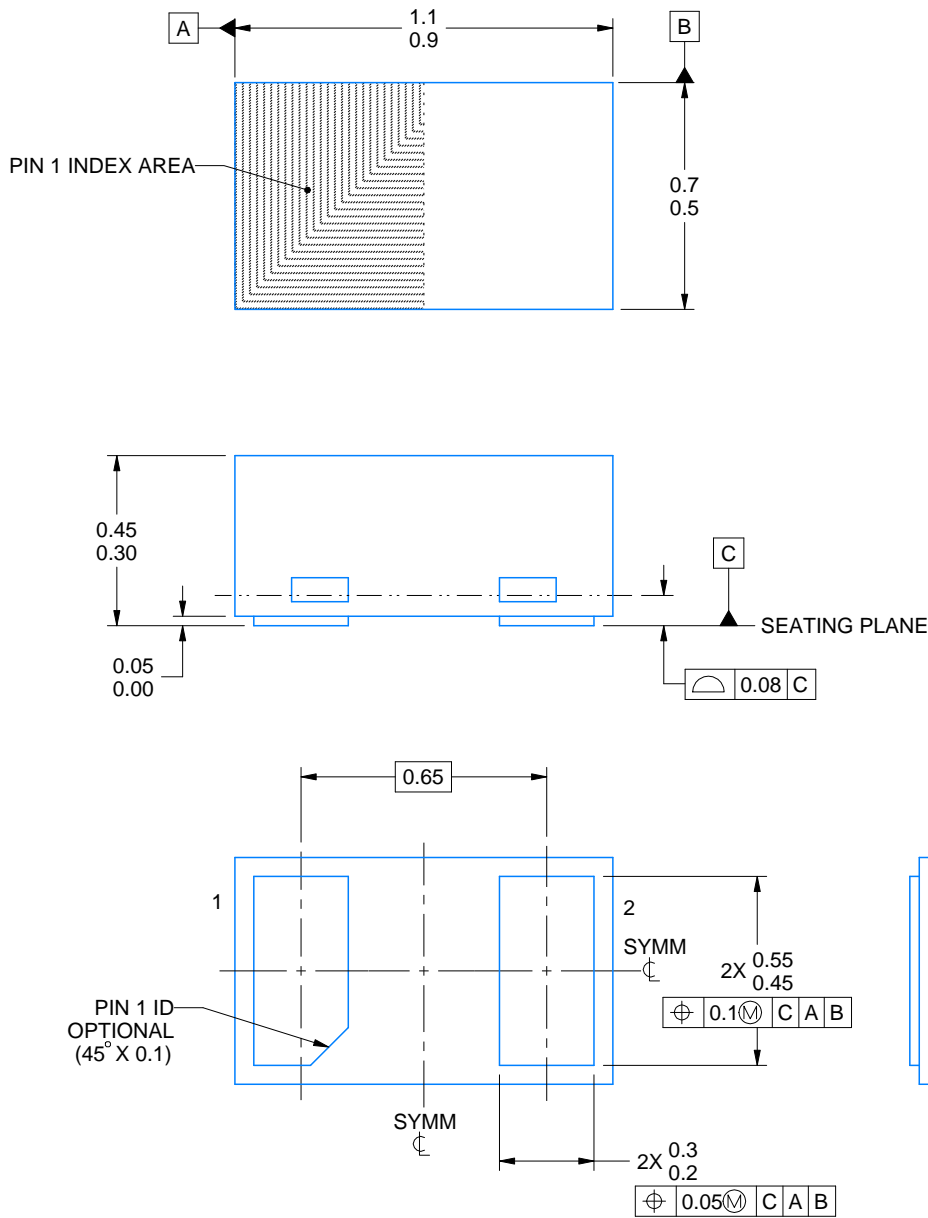
4231484/A

DPY0002A



PACKAGE OUTLINE
X1SON - 0.45 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



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NOTES:

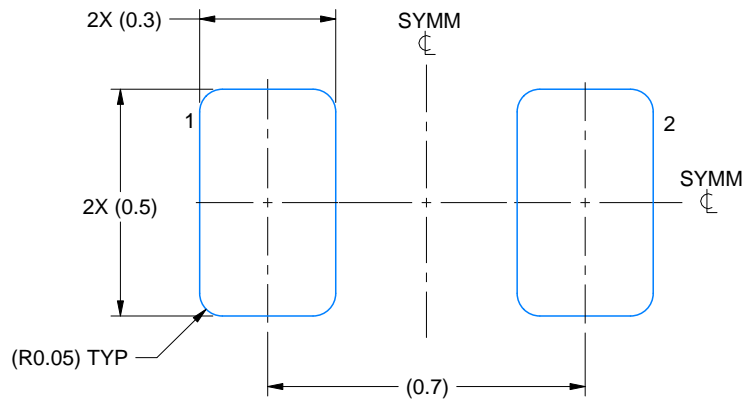
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

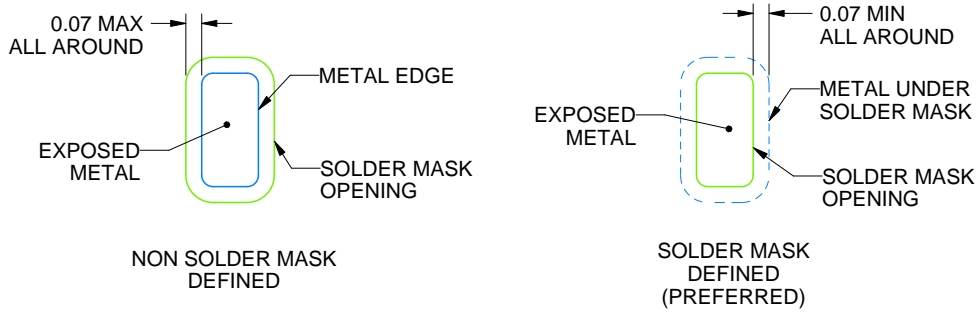
DPY0002A

X1SON - 0.45 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:60X



SOLDER MASK DETAILS

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NOTES: (continued)

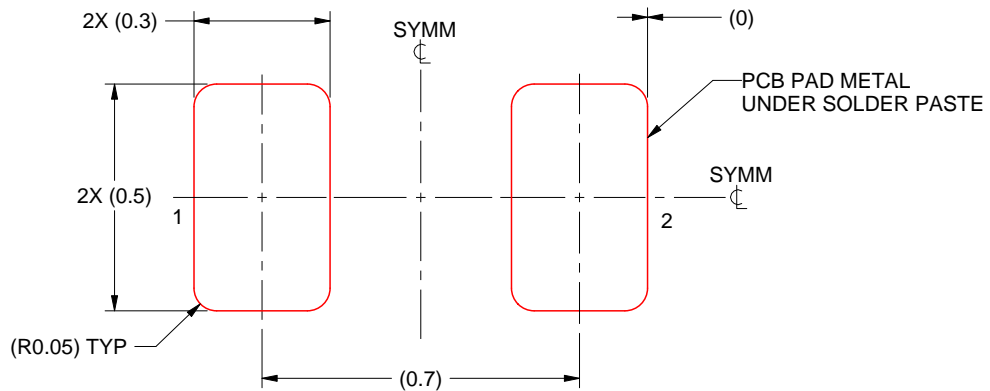
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
4. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DPY0002A

X1SON - 0.45 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:60X

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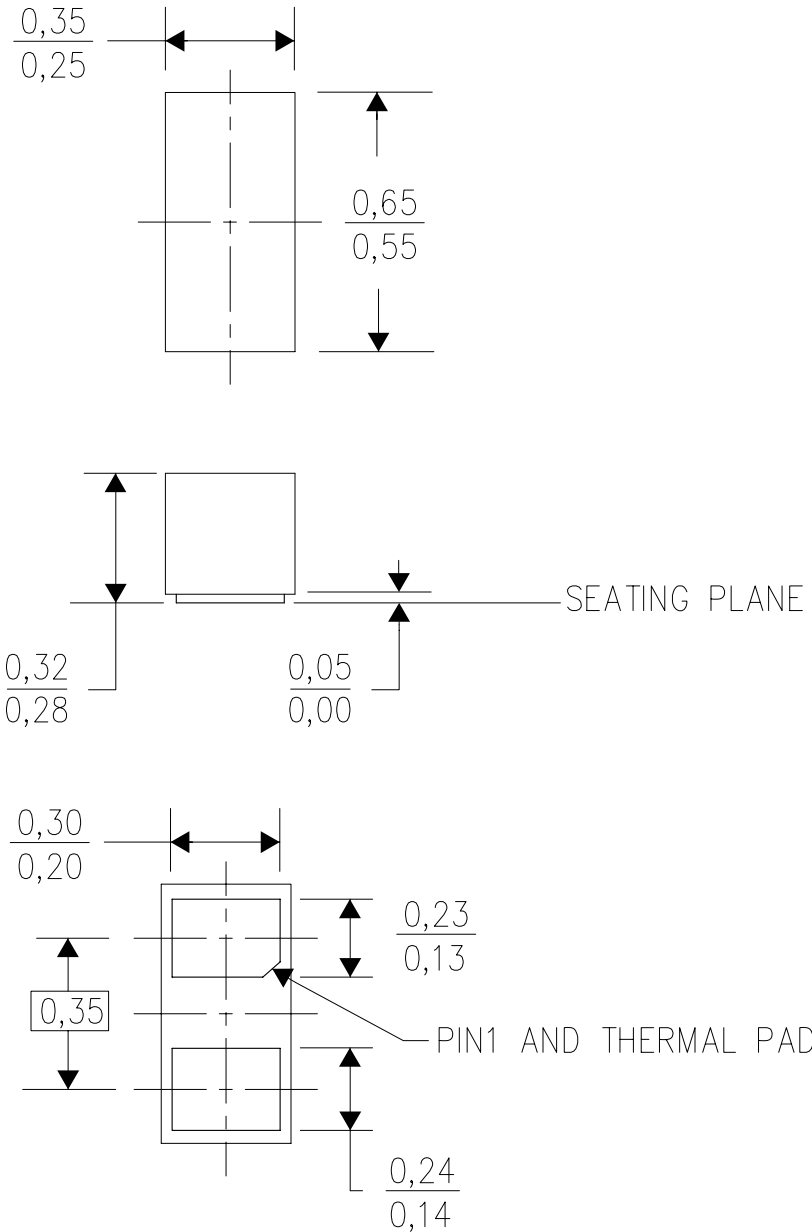
NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

DPL (R-PX2SON-N2)

PLASTIC SMALL OUTLINE NO-LEAD

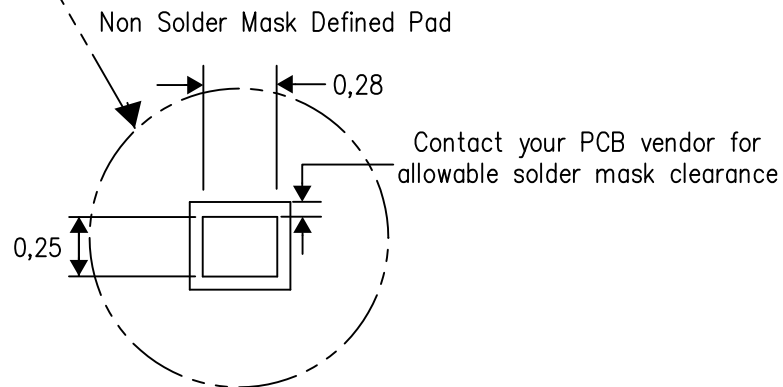
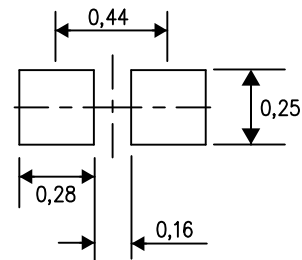
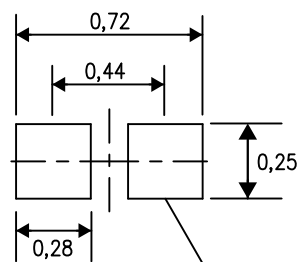


4212149/B 10/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Small Outline No-Lead (SON) package configuration.
 - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.

Example Board Layout

Example Stencil Design
(Note E)



4217903/A 08/12

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
 - E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
 - F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.

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